



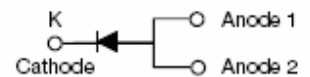
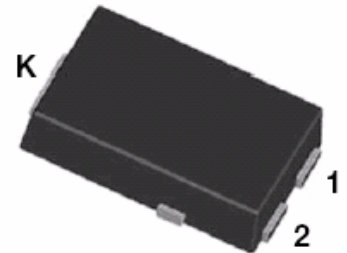
ST1550S SCHOTTKY RECTIFIER

Applications:

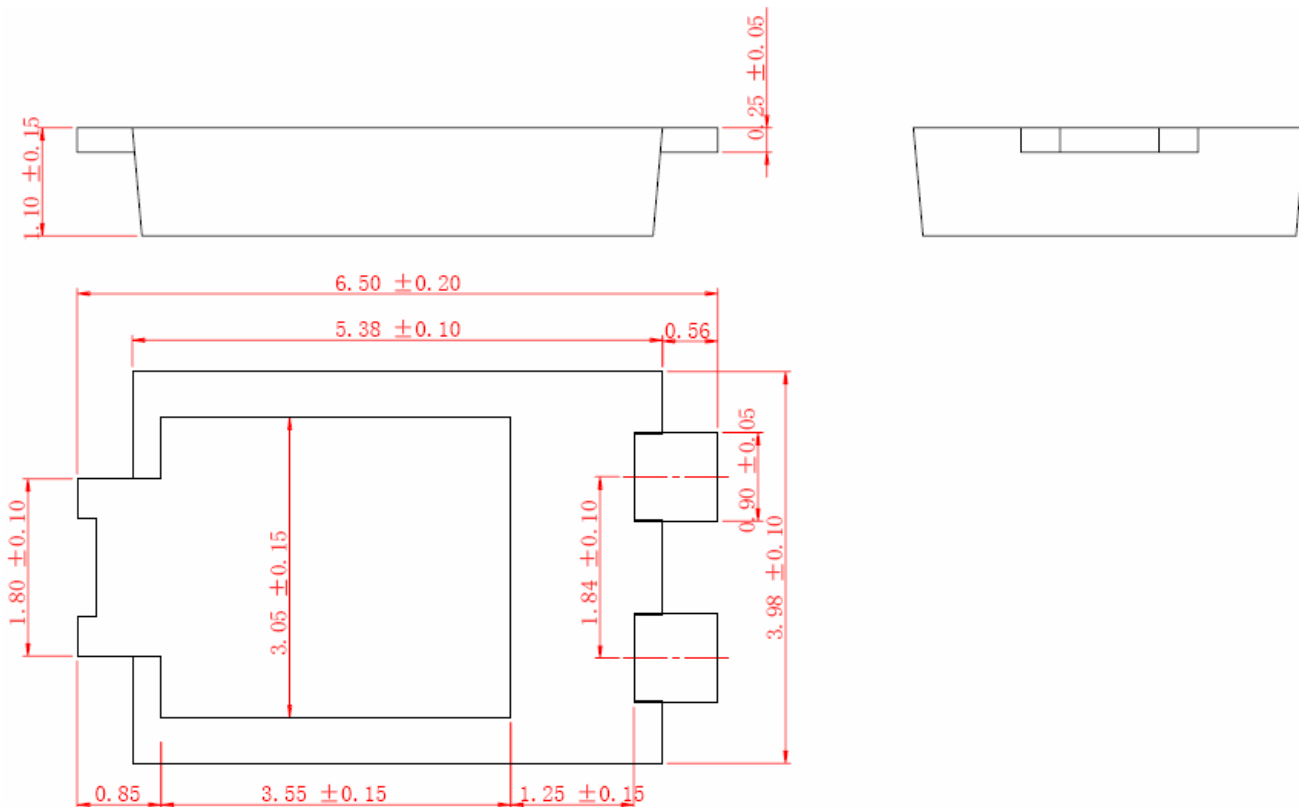
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150°C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm



TO-277B (JK)

Marking Diagram:



Where XXXXX is YYWWL

- S = Device Type
- T = Ultralow VF
- 15 = Forward Current (15)
- 50 = Reverse Voltage (50V)
- S = Package type
- YY = Year
- WW = Week
- L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
ST1550S	TO-277B (Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	50	V
Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 80^\circ C$ rectangular wave form	15	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	200	A



Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 5A, Pulse, $T_J = 25\text{ }^\circ\text{C}$	0.38	0.46	V
		@ 7.5A, Pulse, $T_J = 25\text{ }^\circ\text{C}$	0.41	0.49	
@ 15A, Pulse, $T_J = 25\text{ }^\circ\text{C}$		0.48	0.56		
	V_{F2}	@ 5A, Pulse, $T_J = 125\text{ }^\circ\text{C}$	0.26	0.35	V
		@ 7.5A, Pulse, $T_J = 125\text{ }^\circ\text{C}$	0.31	0.40	
		@ 15A, Pulse, $T_J = 125\text{ }^\circ\text{C}$	0.41	0.50	
Reverse Current (per leg)	I_{R1}	@ $V_R = \text{rated } V_R$ $T_J = 25\text{ }^\circ\text{C}$	0.14	3	mA
Reverse Current (per leg) *	I_{R2}	@ $V_R = \text{rated } V_R$ $T_J = 125\text{ }^\circ\text{C}$	60	140	mA
Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{V}$, $T_C = 25\text{ }^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	-	800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/ μs

* Pulse Width < 300 μs , Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Ambient	$R_{\theta JA}$	DC operation	70	$^\circ\text{C/W}$
Approximate Weight	8	-	0.08	g
Case Style	TO-277B			



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